

AMENDMENTS TO THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application:

LISTING OF CLAIMS:

1. (canceled)
2. (Original) A linear light-emitting element characterized in that a plurality of sections forming a light-emitting region and a light-emitting control region for controlling light-emitting intensity of said light-emitting region are formed in the longitudinal direction continuously or intermittently.
3. (Currently Amended) A linear light-emitting element in claim [[1 or]] 2, wherein the sectional shape is circular, polygonal, star-shaped, crescent, petal, character or any other arbitrary shapes.
4. (Currently Amended) A linear light-emitting element in claim 2 ~~any of claims 1 to 3~~, wherein said light-emitting region is made of an organic EL film.
5. (Currently Amended) A linear light-emitting element in claim 2 ~~any of claims 1 to 3~~, wherein said light-emitting region is made of a multilayered film including an organic EL film.

6. (Original) A linear light-emitting element in claim 5, wherein said multilayered film including the organic EL film is a multilayered film including at least an electron transport layer or an electron injection layer, and said electron transport layer or said electron injection layer is made of an alkali-metal including fullerene or an organic material doped with alkali-metal including fullerene.

7. (Currently Amended) A linear light-emitting element in claim 2 ~~any of claims 1 to 6~~, wherein said light-emitting control region is made of a source region, a semiconductor region, a gate electrode and a drain region formed in the section, in which said source region is provided at the center and said semiconductor region, said light-emitting region and said drain region are sequentially formed outside thereof and a plurality of said gate electrodes are arranged within said semiconductor region surrounding said source region.

8. (Currently Amended) A linear light-emitting element in claim 2 ~~any of claims 1 to 6~~, wherein said light-emitting control region is made of a source region, a semiconductor region, a gate electrode and a drain region formed in the section, in which a first central region is provided at the center and said source region, said semiconductor region, said light-emitting region and said drain region are sequentially formed outside thereof, a plurality of said gate electrodes are arranged within said semiconductor region surrounding said source

region, and said first central region is made of a hollow region, insulator region, semiconductor region or conductor region.

9. (Currently Amended) A linear light-emitting element in claim 2 ~~any of claims 1 to 6~~, wherein said light-emitting control region is made of a drain region, a semiconductor region, a gate electrode and a source region formed in the section, in which said drain region is provided at the center and said semiconductor region, said light-emitting region and said source region are sequentially formed outside thereof, and a plurality of said gate electrodes are arranged within said semiconductor region surrounding said drain region.

10. (Currently Amended) A linear light-emitting element in claim 2 ~~any of claims 1 to 6~~, wherein said light-emitting control region is made of a drain region, a semiconductor region, a gate electrode and a source region formed in the section, in which a first central region is provided at the center and said drain region, said semiconductor region, said light-emitting region and said source region are sequentially formed outside thereof, a plurality of said gate electrodes are arranged within said semiconductor region surrounding said drain region and said first central region is made of a hollow region, insulator region, semiconductor region or conductor region.

11. (Currently Amended) A linear light-emitting element in claim 2 ~~in any of claims 7 to 10~~, wherein said light-

emitting region is made of a red light-emitting region, a green light-emitting region and a blue light-emitting region.

12. (Original) A linear light-emitting element in claim 11, wherein said red light-emitting region, said green light-emitting region and said blue light-emitting region are arranged in a first sectional region obtained by dividing said section with a straight line passing through the center of said section, and a reflection region is arranged in an opposing second sectional region.

13. (Currently Amended) A linear light-emitting element in ~~any of claims 7 to~~ claim 7 or 8, wherein a red transmission filter region, a green transmission filter region and a blue transmission filter region are arranged surrounding said drain region.

14. (Currently Amended) A linear light-emitting element in ~~any of claims 9 to~~ claim 9 or 10, wherein a red transmission filter region, a green transmission filter region and a blue transmission filter region are arranged surrounding said source region.

15. (Currently Amended) A linear light-emitting element in claim 7 ~~any of claims 7 to 14~~, wherein said semiconductor region is made of an N-type semiconductor material and said gate electrode is made of a P-type semiconductor material.

16. (Currently Amended) A linear light-emitting element in claim 7 ~~any of claims 7 to 14~~, wherein said semiconductor region is made of a P-type semiconductor material and said gate electrode is made of an N-type semiconductor material.

17. (Currently Amended) A linear light-emitting element in claim 7 ~~any of claims 7 to 14~~, wherein said semiconductor region is made of an N-type semiconductor material and said gate electrode is made of a conductive material.

18. (Currently Amended) A linear light-emitting element in claim 7 ~~any of claims 7 to 14~~, wherein said semiconductor region is made of a P-type semiconductor material and said gate electrode is made of a conductive material.

19. (Currently Amended) A linear light-emitting element in claim 2 ~~any of claims 1 to 6~~, wherein said light-emitting control region is made of a gate electrode, a gate insulating film, an anode and a cathode formed in the section, said gate electrode is provided at the center, said gate insulating film, said anode having an opening, said light-emitting region and said cathode are sequentially formed outside thereof, and said cathode is formed on said light-emitting region in contact with said anode opening.

20. (Currently Amended) A linear light-emitting element in claim 2 ~~any of claims 1 to 6~~, wherein said light-emitting control region is made of a gate electrode, a gate insulating film, an anode and a cathode formed in the section, a first central region is provided at the center, said gate electrode, said gate insulating film, said anode having an opening, said light-emitting region and said cathode are sequentially formed outside thereof, said cathode is formed on said light-emitting region in contact with said anode opening, and said first central region is made of a hollow region, insulator region, semiconductor region or conductor region.

21. (Currently Amended) A linear light-emitting element in claim 2 ~~any of claims 1 to 6~~, wherein said light-emitting control region is made of a gate electrode, a gate insulating film, an anode and a cathode formed in the section, said gate electrode is provided at the center, said gate insulating film, said cathode having an opening, said light-emitting region and said anode are sequentially formed outside thereof, and said anode is formed on said light-emitting region in contact with said cathode opening.

22. (Currently Amended) A linear light-emitting element in claim 2 ~~any of claims 1 to 6~~, wherein said light-emitting control region is made of a gate electrode, a gate insulating film, an anode and a cathode formed in the section, a first central region is provided at the center, said gate electrode, said gate insulating film, said cathode having an

opening, said light-emitting region and said anode are sequentially formed outside thereof, said anode is formed on said light-emitting region in contact with said cathode opening, and said first central region is made of a hollow region, insulator region, semiconductor region or conductor region.

23. (Currently Amended) A light-emitting device made of a linear light-emitting element in claim 2 ~~any of claims 1 to 22~~.

24. (Original) A light-emitting device in claim 23, wherein it is a display device.

25. (Original) A light-emitting device in claim 23, wherein it is an illuminating device.

26.-41. (Canceled)